NSN 5961-01-021-6663

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-021-6663 **Inclosure Material:** Glass **Overall Length:** Between 0.315 inches and 0.350 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.215 inches and 0.225 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 190.0 breakdown voltage, dc and 210.0 breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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